
	<h2 style="color: red;">SI1050X-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1050X-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 8V 1.34A SC-89-6</p> <p>Datenblätter:  SI1050X-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6980 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1050X-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 8V 1.34A SC-89-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	6980 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	N-Channel 8V 1.34A (Ta) 236mW (Ta) Surface Mount
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Verlustleistung (max)	236mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.34A (Ta)
Rds On (Max) @ Id, Vgs	86 mOhm @ 1.34A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11.6nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	585pF @ 4V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±5V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1050X-T1-GE3CT



SI1050X-T1-GE3 ist neu im Original, Suche SI1050X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1050X-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1050X-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1051X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 1.2A SC89-6</p>	 <p>SI1054X-T1-E3 Vishay / Siliconix MOSFET N-CH 12V 1.32A SC89-6</p>	 <p>SI1050X-T1-E3 Vishay / Siliconix MOSFET N-CH 8V 1.34A SOT563F</p>	 <p>SI1050X-T1-GE3 Vishay / Siliconix MOSFET N-CH 8V 1.34A SC-89-6</p>
 <p>SI1051X-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 1.2A SC89-6</p>	 <p>SI1051X-T1-GE3 Vishay / Siliconix MOSFET P-CH 8V 1.2A SC89-6</p>	 <p>SI1046X-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 0.606A SC89-3</p>	 <p>SI1051X-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 1.2A SC89-6</p>

heiße Teile

Mehr

 SI1034X-T1-E3	 SI1034X-T1-E3	 SI1034X-T1-GE3	 SI1034X-T1-GE3	 SI1035X-T1
 SI1035X-T1-E3	 SI1035X-T1-E3	 SI1035X-T1-GE3	 SI1035X-T1-GE3	 SI1039X-T1-E3
 SI1039X-T1-E3	 SI1040X-T1-E3	 SI1040X-T1-E3	 SI1040X-T1-GE3	 SI1040X-T1-GE3
 SI1041ADY	 SI1041DY-T1	 SI1041DY-T1-E3	 SI1045AB	 SI1045ADY-T1
 SI1046X-T1-E3	 SI1046X-T1-GE3	 SI1046X-T1-GE3	 SI1050X-T1-E3	 SI1050X-T1-E3
 SI1050X-T1-GE3	 SI1051X-T1-GE3	 SI1051X-T1-GE3	 SI1056X-T1-E3	 SI1056X-T1-E3
 SI1056X-T1-GE3	 SI1056X-T1-GE3	 SI1058X-T1-GE3	 SI1058X-T1-GE3	 SI1065X-T1-E3
 SI1065X-T1-E3	 SI1065X-T1-GE3	 SI1065X-T1-GE3	 SI1067X-T1-E3	 SI1067X-T1-E3
 SI1067X-T1-GE3	 SI1067X-T1-GE3	 SI1069X-T1-E3	 SI1069X-T1-E3	 SI1069X-T1-GE3
 SI1069X-T1-GE3	 SI1070X-T1-E3	 SI1070X-T1-E3	 SI1070X-T1-GE3	 SI1070X-T1-GE3

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